

# 10V Drive Nch MOSFET

### **R5013ANJ**

#### Structure

Silicon N-channel MOSFET

#### Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (VGSS) guaranteed to be  $\pm 30$ V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

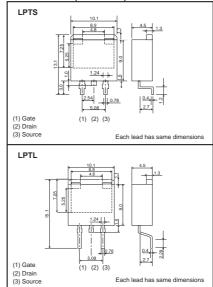
#### Applications

Switching

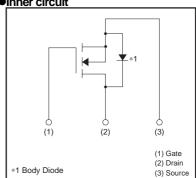
#### Packaging specifications

	Package	Taping			
Туре	Cada	LPTS	TL		
	Code	LPTL	TLL		
	Basic ordering unit (pieces)	1000			

#### ●Dimensions (Unit: mm)



#### ●Inner circuit



#### ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbo	ı	Limits	Unit	
Drain-source voltage	Voss		500	V	
Gate-source voltage	Vgss		±30	V	
Drain augrent	Continuous	lσ	*3	±13	А
Drain current	Pulsed	IDP	*1	±52	А
Source current	Continuous	ls	*3	13	А
(Body Diode)	Pulsed	İsp	*1	52	А
Avalanche current	las	*2	6.5	А	
Avalanche energy	Eas	*2	11.3	mJ	
Total power dissipation	Po		100	W	
Channel temperature	Tch		150	°C	
Range of storage tem	Tstg		-55 to +150	°C	

- \*1 Pw≤10μs, Duty cycle≤1%

  \*2 L≒ 500μH, Vpo=50V, Re=25Ω, Starting, Tch=25°C

  \*3 Limited only by maximum temperature allowed

#### Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to case	Rth(ch-c)	1.25	°C/W

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	Igss	-	_	±100	nA	Vgs=±30V, Vps=0V	
Drain-source breakdown voltage	V(BR)DSS	500	_	_	V	In=1mA, Vgs=0V	
Zero gate voltage drain current	IDSS	_	_	100	μΑ	VDS=500V, VGS=0V	
Gate threshold voltage	VGS(th)	2.5	_	4.5	V	VDS=10V, ID=1mA	
Static drain-source on-state resistance	RDS(on)*	_	0.29	0.38	Ω	In=6.5A, Vgs=10V	
Forward transfer admittance	Yfs   *	4.0	_	_	S	Vps=10V, lp=6.5A	
Input capacitance	Ciss	-	1300	_	pF	VDS=25V	
Output capacitance	Coss	_	500	_	pF	Vgs=0V	
Reverse transfer capacitance	Crss	_	40	_	pF	f=1MHz	
Turn-on delay time	td(on) *	_	30	_	ns	V <sub>DD</sub> ≒250V, I <sub>D</sub> =6.5A	
Rise time	tr *	_	32	_	ns	Vgs=10V	
Turn-off delay time	td(off) *	-	90	_	ns	RL=38.5Ω	
Fall time	t <sub>f</sub> *	_	30	-	ns	R <sub>G</sub> =10Ω	
Total gate charge	Qg *	_	35	_	nC	V <sub>DD</sub> ≒250V	
Gate-source charge	Qgs *	_	8	_	nC	I <sub>D</sub> =13A   V <sub>G</sub> s=10V   R <sub>L</sub> =19.2Ω / R <sub>G</sub> =10Ω	
Gate-drain charge	Q <sub>gd</sub> *		15		nC		

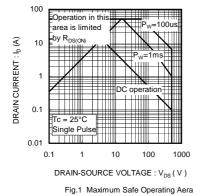
<sup>\*</sup> Pulsed

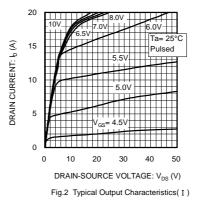
# ●Body diode characteristics (Source-drain) (Ta=25°C)

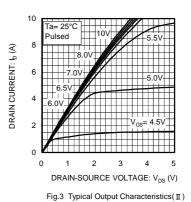
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	1.5	V	Is= 13A, V <sub>GS</sub> =0V

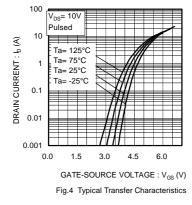
<sup>\*</sup> Pulsed

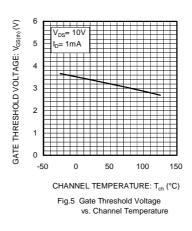
#### Electrical characteristic curves

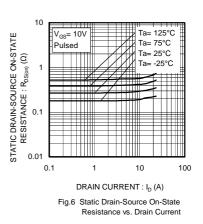


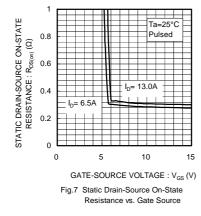


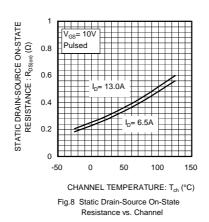


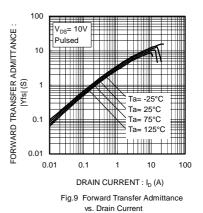


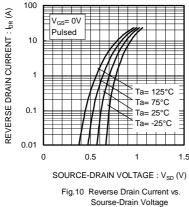




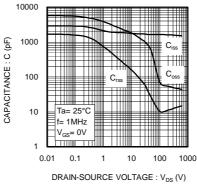








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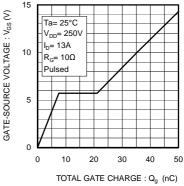
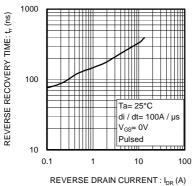


Fig.11 Typical Capacitance vs Drain-Source Voltage

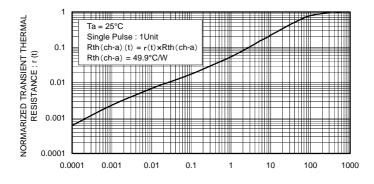
Fig.12 Dynamic Input Characteristics



10000 Ta= 25°C V<sub>GS</sub>= 10V SWITCHING TIME : t (ns) 1000  $R_G = 10\Omega$ Pulsed 100 10 0.01 DRAIN CURRENT : I<sub>D</sub> (A)

Fig.13 Reverse Recovery Time vs.Reverse Drain Current

Fig.14 Switching Characteristics



PULSE WIDTH: Pw(s) Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

R5013ANJ Data Sheet

#### •Switching characteristics measurement circuit

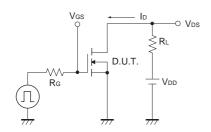


Fig.1-1 Switching time measurement circuit

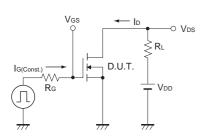


Fig.2-1 Gate charge measurement circuit

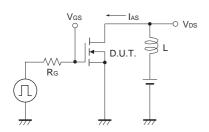


Fig.3-1 Avalanche Measurement circuit

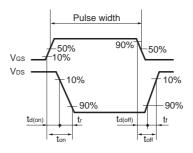


Fig.1-2 Switching waveforms

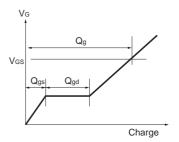


Fig.2-2 Gate charge waveform

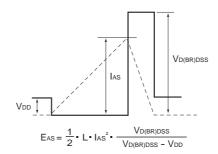


Fig.3-2 Avalanche waveform

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